

ENS220

Premium accuracy barometric pressure and temperature sensor for activity tracking and indoor navigation / localization

ENS220 datasheet

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The ENS220 is an ultra-low-power, high-accuracy barometric pressure and temperature sensor. It comes in the smallest size LGA package with digital I²C and SPI interfaces. This enables new use cases in activity tracking, indoor navigation/localization, fall- and liquid-level detection.

The capacitive pressure sensor of the ENS220 is integrated on a CMOS ASIC. This single die solution not only allows small form factor packages with excellent immunity to changes in environmental conditions, but also achieves ultra-low current consumption due to the capacitive read-out. High intrinsic pressure sensitivity combined with an ultra-low noise 24-bit ADC converter results in unprecedented low pressure noise. The integrated temperature sensor matches the performance of dedicated temperature measurement devices. It ensures a stable, temperature compensated pressure output with a fast response time. The highly accurate pressure reading, and the short conversion time make the ENS220 perfect for height measurements with a high output data rate and high bandwidth.

Key Features & Benefits

Premium **absolute accuracy:** ±0.5 hPa

Relative accuracy: ±0.025 hPa (equiv. to ±20 cm in air) allows ultra-fine differential pressure measurements for reliable **centimeter resolution positioning**

Lowest power: average supply current of 0.1 µA at idle, 0.8 µA when sampling at 1/60 Hz, ensures **long battery life** even at high sampling rates

Ultra-low noise of 0.1 Pa rms (≈ 1 cm) at 2 Hz sample rate

User-configurable sample rate up to 1 kHz (0.9 Pa rms)

Temperature accuracy of ±0.1 K with 8 mK resolution

Fully digital interface with **best-of-breed form factor**, which perfectly integrates into **space-constrained designs**, e.g., mobiles, wearables, hearables

Interrupt output on multiple conditions, **including pressure thresholds** for ultralow power applications

Applications

- Mobile/Wearables: activity tracking, indoor localization/navigation, fall detection
- Gaming, AR/VR, Drones: height tracking
- Appliances/HVAC: filter clogging detection, building balancing
- White goods: liquid level detection
- Personal health care: blood pressure $measured$ measurement¹
- Accurate temperature meter for gasses and surfaces

Properties

- Small $2.0 \times 2.0 \times 0.75$ mm³ LGA package
- P operating range from 300 to 1200 hPa
- T operating range from −40 to +85 °C
- Power supply range from 1.62 V to 1.98 V, interface voltage up to 3.6 V
- Standard, fast, and high speed l^2C and SPI interface
- T&R packaged, reflow solderable.
- MSL1 compliant

¹ Consumer grade product, not medically qualified. Customer must ensure compliance.

Content Guide

 $\overline{4}$

1 Quick Start

A typical application circuit for ENS220 is shown on the left-hand side of Figure 1. After reaching the minimal supply voltage and allowing for the maximal power-up time of 1 ms the sensor is ready for $I²C$ communication. The quickest way to measure pressure and temperature is pseudo-coded in Figure [1.](#page-4-1) The conversion formula given in the equations in [Table 5](#page-11-3) and [Table 6](#page-11-4) are used to translate the digital signals into absolute pressure and temperature readings.

More application examples can be found in chapter [9.](#page-42-0)

Figure 1: Typical application circuit (top) and pseudo code (bottom) for easy starting. For details on the sensor configuration see section [6.](#page-9-0)

Find code resources and drivers on: <https://github.com/sciosense/ens220-arduino>

2 Pin assignment

Figure 2: Pin diagram (NC = not connected)

Consult section [9](#page-42-0) for wiring.

Table 1: Pin description

3 Pressure and temperature specifications

Default conditions apply to values in [Table 2,](#page-6-1) unless otherwise stated: 25 °C, 50 % RH, no MSL1 preconditioning, default periodic measurement.

Table 2: Pressure and temperature specifications

Symbol	Parameter	Conditions	Min	Typ	Max	Unit			
	Pressure								
PRANGE	Pressure operating range		300		1200	hPa			
P_{ABS}	Absolute pressure accuracy ²	5001100 hPa, -5+55 °C		±0.5		hPa			
		5001100 hPa, -20+70 °C		±1		hPa			
		3001200 hPa, -40+85 °C		±3		hPa			
P_{REL}	Relative accuracy	P step of 10 hPa, 6001100 hPa, -5+55 °C		2.5		Pa			
P _{RES}	Pressure resolution	1 LSB		1/64		Pa			
PSOLDER	Absolute pressure accuracy after soldering ³	1000 hPa, 25 °C		±1		hPa			
P _{DRIFT}	Long term stability ⁴			±10		Pa/year			
TSENS	Temperature sensitivity	5001100 hPa, 2545 °C		0.5		Pa/K			
PNOISE	RMS pressure noise	4 ms conversion, no over- sampling, 1000 hPa, 25 °C 5		0.85		Pa			
		Temperature							
TRANGE	Temperature operating range		-40		$+85$	$^{\circ}C$			
T_{ACC}	Absolute temperature accuracy	$-5+55$ °C	-0.2	±0.1	$+0.2$	$^{\circ}C$			
		$-40+85$ °C	-0.5		$+0.5$	$^{\circ}C$			
T _{RES}	Temperature resolution			1/128		Κ			

ENS220 Datasheet SC-001717-DS-21 / 2023-09-19 / Production 7

² After calibration at component-level, not including the influence of soldering and lifetime use.

³ 168 h after soldering. The sensor is calibrated at factory for the temperature profile given in [Figure 31.](#page-47-1) ⁴ Average over lifetime, based on temperature-accelerated measurements.

 5 Results in ODR \approx 40...250 Hz. See chapter [9.4](#page-44-0) for recommended application settings.

4 Electrical characteristics

[Table 3](#page-7-1) details the electrical characteristics of the ENS220. The min and max parameter values are guaranteed by production tests or SQC (Statistical Quality Control) methods.

Table 3: Electrical characteristics

At power-up, the supply voltage (V_{DD}) must rise within t_{VddTr} = 10 ms to the minimum supply voltage. Otherwise, the internal reset may malfunction.

⁶ See [Figure 28.](#page-42-3) SCL and SDA should be set to 0 V when the device is powered off (V_{DD} = 0 V). Otherwise, current may flow from the (3.6 V) bus into SDA or SCL.

5 Absolute maximum ratings

Table 4: Absolute Maximum Ratings

Stresses beyond those listed in [Table 4: Absolute Maximum Ratings](#page-8-1) may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under [Table 3: Electrical characteristics](#page-7-1) are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability and lifetime.

Note: The ENS220 is not designed for use in safety-critical or life-protecting applications.

ENS220 Datasheet SC-001717-DS-21 / 2023-09-19 / Production 9

 7 V_{IO} _{PP} should not exceed the absolute maximum rating of V_{DD}. ⁸ The ENS220 is electrically operable in this range, however its pressure sensing performance might vary.

6 Functional description

The ENS220 integrates an absolute pressure sensor, a temperature sensor and an ASIC which performs A/D conversions and provides the pressure and temperature data through a digital interface.

Figure 3: Block diagram of the ENS220

The ENS220 is a sensor capable of providing fast and accurate temperature measurements at low current consumption. To meet the requirements of different use cases the ENS220 offers very high configuration flexibility.

The configurable features are:

- Operating mode
	- o Continuous
	- o Pulsed
	- o Single Shot
- Pressure measurement precision (conversion time and oversampling) and rate
- Temperature measurement precision (oversampling) and rate
- Ultra-low power mode
- **FIFO**
- Interrupt behavior
	- o New measurement available
	- o FIFO at watermark level
	- o FIFO full
	- o High resolution pressure threshold
	- o No interrupt
	- Moving average

6.1 Measurement modes

The sensor starts powering-up after reaching the power-up threshold voltage V_{DD} , Min = 1.62 V. The sensor enters the default idle mode, in which no measurements are performed, and the sensor configuration can be chosen.

By switching the [START](#page-27-0) bit to 1, the sensor starts measuring pressure and temperature. The ENS220 can be operated in three measurement modes, which can be selected with the value of [STBY_T](#page-30-0) (see also [Figure 4\)](#page-10-2):

Figure 4: Simplified schematic of measurement modes

- If [STBY_T](#page-30-0) = 0 the device performs **continuous** measurements (temperature and pressure).
- If STBY $T > 1$ the device alternates a measurement phase and a standby phase (**pulsed** operation)
- If [STBY_T](#page-30-0) = 1 the device performs a **single** measurement (temperature and pressure) and goes back into idle mode.

The length of the standby phase can be selected from 10 ms to 600 s by writing on [STBY_T.](#page-30-0) A timing diagram of pulsed operation is shown below in [Figure 5.](#page-11-5)

6.2 PT-Rate

In default configuration (see default values in register table), the device performs one pressure measurement followed by a temperature measurement. The ratio between pressure and temperature measurements can be altered by selecting a pressure/temperature rate by writing on [PT_RATE.](#page-28-0) The value varies from 1 to 256. The device will perform a new temperature measurement once every [PT_RATE](#page-28-0) pressure measurements (see [Figure 5\)](#page-11-5).

Figure 5: Effect of PT_RATE = 1 (meaning P/T rate is 4)

[MEAS_P](#page-27-0) and [MEAS_T](#page-27-0) determine whether pressure or temperature measurements take place. If only temperature or only pressure is enabled, [PT_RATE](#page-28-0) has no effect.

The ENS220 uses the temperature value to compensate the pressure output. It is therefore advisable to take regular temperature measurements (at least once per second) to correct temperature fluctuations. For fast temperature transients the temperature measurement should be performed more often to avoid errors in the temperature compensation. The best setting for the temperature update rate depends on the use case and the physical properties of the soldering substrate. It should be evaluated by the user. See also use case examples in chapter [9.](#page-42-0)

If only pressure measurements are enabled ($MEAS_P=0$), the device will begin with a temperature measurement, then it will continue only measuring the pressure. See also [Figure 8.](#page-13-1)

6.3 Readout

6.3.1 Absolute Pressure

The pressure value is a 24 bit unsigned integer and is available in the sensor readout registers [PRESS_OUT](#page-39-1) and [PRESS_OUT_F.](#page-41-0)

The PRESS OUT value is already calibrated, linearized, and temperature compensated. It requires a division by 64 to achieve a pressure reading in Pa:

Table 5: Pressure conversion formula

6.3.2 Temperature

The temperature value is a 16-bit unsigned integer and is available in the sensor readout registers [TEMP_OUT.](#page-40-0) Temperature can be calculated as:

Table 6: Temperature conversion formulas

6.4 Ultra low power mode

Power consumption can be reduced at the expense of some functionality.

If the [HP](#page-27-0) bit is 0 (see MODE CFG), the power consumption in idle and standby state is low (current draw is I_{DD-ULP}) and only the following registers are accessible via SPI/I²C: [MODE_CFG,](#page-27-0) [PART_ID,](#page-26-1) [DATA_STAT,](#page-37-0) [FIFO_STAT,](#page-38-0) [PRESS_OUT,](#page-39-1) [TEMP_OUT,](#page-40-0) [INT_STAT.](#page-39-0)

The use of this feature is recommended for every measurement mode except continuous mode.

By setting [HP](#page-27-0) to 1, the power consumption increases to I_{DDLP} and all registers become available.

- **6.5 Precision and oversampling rate**
	- **6.5.1 Absolute Pressure**

The precision of the pressure output can be optimized by adjusting the conversion time and the oversampling rate. The conversion times are multitudes of the (base) pressure conversion time $t_{\text{CONV-P}}$ or the temperature conversion time $t_{\text{CONV T}}$ as specified in [Table 2.](#page-6-1) The numbers below are typical values.

The ENS220 has a default conversion time t_P of 2 ms for pressure conversion. The conversion time can be selected via P_{CONV} to 1 ms, 2 ms or 4 ms. The first measurement after ADC power-up (i.e., after exiting standby mode or after a temperature measurement) requires 4 times the nominal duration (see [Figure 6](#page-12-3) and [Figure 7\)](#page-12-4).

Figure 6: Timing diagram of a pressure pulse (values are typical)

Figure 7: Typical timing for a continuous or pulsed measurement in default configuration (PT_RATE = 1, P_CONV = 1 (≈ 2 ms) and no oversampling)

Oversampling is available to reduce the measurement noise at the expense of conversion time. Between 1 and 128 measurements (see also [OVS_CFG\)](#page-31-0) are performed and averaged to calculate the output value. Every additional conversion for oversampling takes 1 ms, 2 ms or 4 ms, depending on the conversion time selected [\(Figure 8\)](#page-13-1). The effect of oversampling on noise is shown in [Figure 9.](#page-13-2)

Figure 8: Typical timings for a continuous pressure-only measurement ([MEAS_](#page-27-0)T *= 0,* [P_CONV](#page-28-0) *= 0) with activated 2× oversampling (*[OVSP](#page-31-0) *= 1)*

Figure 9: Pressure noise as function of oversampling ratio for three conversion time settings

The oversampled pressure value can either be transferred directly to the readout registers, can be recorded in a FIFO buffer, or can be further processed by a moving average filter. The desired path is selected by writing on [MODE_CFG.FIFO_MODE](#page-27-0) (see chapter [6.6](#page-14-0) and [6.8\)](#page-16-0).

6.5.2 Temperature

The precision of the temperature output can be optimized by oversampling rate. Between 1 and 128 measurements (see also [OVS_CFG\)](#page-31-0) are performed and averaged to calculate the output value. The temperature conversion time is 4 ms. In case of oversampling, every additional conversion requires 1 ms (see [Figure 10\)](#page-13-3).

Figure 10: Timing diagram of a temperature pulse (values are typical)

Note: Each temperature measurement will take 3 ms plus the number of over-samples [\(Figure 11\)](#page-14-1). This holds for any measurement mode, including temperature-only measurements.

Figure 11: Typical timing of a continuous temperature-only measurement ([MEAS_P](#page-27-0)*=0) with 8× oversampling (*[OVST](#page-31-0)*=3)*

6.6 FIFO

A FIFO buffer is available to store 32 pressure values. It is enabled by [MODE_CFG.FIFO_MODE.](#page-27-0)

The FIFO works as a circular buffer, with a write pointer to store new pressure values and a read pointer to retrieve them. The structure is shown in [Figure 12.](#page-14-2) The write pointer increases whenever a new measurement is completed and the new value is written to the buffer. The pointer will increase even when the buffer is full, overwriting the oldest values recorded. Reads from PRESS OUT H increase the read pointer until it reaches the write pointer, subsequent reads will return 0. Both pointers wrap around (31 increments to 0).

The entire FIFO can be quickly read from PRESS OUT F. A continuous read past address 0x29 will cycle the memory read pointer back to 0x27, increasing at the same time the FIFO read pointer. In this way the entire FIFO buffer can be transferred without addressing overhead.

NOTE: In order to read more than one value it is necessary to set the [HP](#page-27-0) bit in [MODE_CFG.](#page-27-0)

Figure 12: FIFO structure

FIFO operations are controlled by [FIFO_CFG.](#page-36-0) The FIFO can be cleared by setting [FP_CLEAR.](#page-36-0) The FIFO status is available in [FIFO_STAT,](#page-38-0) and the current FIFO fill level (number of elements available) can be read from [FP_FILL.](#page-38-0) When the FIFO is empty, [FE](#page-38-0) is set. When the FIFO is full, [FF](#page-38-0) is set. If a new pressure value arrives while FIFO is full, the overrun bit [DATA_STAT.PO](#page-37-0) is set, and the oldest value is overwritten.

Figure 13: Sample FIFO timing diagram

Interrupts can be asserted when the FIFO is full, empty, or filled to a certain level. See chapter [6.7.](#page-15-0)

6.7 Interrupt

Interrupts can be enabled by writing on [INT_CFG.](#page-34-0) Interrupts are available for the following events:

- Pressure measurement ready
- Temperature measurement ready
- FIFO level high
- FIFO full
- FIFO empty
- Pressure below [PRESS_LO](#page-35-0)
- Pressure above [PRESS_HI](#page-35-1)

Register [INTF_CFG](#page-33-0) controls if the interrupt is signalled on the hardware pin INT. It also sets the polarity of this pin.

Once an interrupt is asserted, the interrupt source can be read in [INT_STAT.](#page-39-0)

Reading [INT_STAT](#page-39-0) will automatically clear all interrupt source flags, will clear [IA,](#page-39-0) and will reset the INT/SDO pin value to the de-asserted state.

Figure 14: Sample interrupt timing diagram

6.8 Moving average

A moving average filter can be applied to pressure measurements. The filter is enabled by writing on [MODE_CFG.FIFO_MODE.](#page-27-0) The FIFO buffer is used to implement this function, so FIFO is not available when the moving average filter is enabled.

The window size, i.e., the number of samples used by the moving average filter, is controlled by [MAVG](#page-32-0) (1 to 32). It should only be changed while the moving average filter is disabled. After the moving average filter is enabled by setting MODE CFG.FIFO MODE = 2, the first pressure value available is used to initialize the window with that first pressure value.

NOTE: moving average settings are independent from pressure oversampling enabled via [OVSP.](#page-31-0) The result of pressure oversampling is processed by the moving average filter.

7 Digital interface description

The ENS220 can be accessed as a slave device through either SPI 3-wire, SPI 4-wire, or I^2C serial interface.

7.1 Interface selection

Selection between I²C and SPI is done through CSN.

If CSN is high, the I^2C interface will be active and the SPI interface inactive. For systems where the host communicates via I^2C to this device, connect CSN to VDD permanently.

A falling edge of CSN will disable the I²C interface until the next power-on cycle or software reset. The SPI host should generate a low pulse on CSN before communicating to other devices on the bus. The device may otherwise interpret SPI bus traffic as I^2C commands.

7.2 I ²C interface

The EN220 is an I^2C slave device with a fixed 7-bit address 0x20.

The I²C interface supports fast (400 kbit/s) and high-speed (3400 kbit/s) mode. Details on I²C protocol is according to 12 C-bus specifications [UM10204, 12 C-bus specification and user manual, Rev. 6, 4 April 2014].

The device applies all mandatory I²C protocol features for slaves: START, STOP, Acknowledge, 7-bit slave address. None of the other optional features (10-bit slave address, general call, software reset or Device ID) are supported, nor are the master features (Synchronization, Arbitration, START byte).

The ENS220 uses a register model to interact with the host. This means that the I²C master can directly read or write values to one of the registers by first sending the single byte register address. The ENS220 implements an "auto increment" which allows reading or writing multiple bytes in a single transaction. This provides an effective way to read pressure or temperature values. See chapters [6.3,](#page-11-0) [6.6.](#page-14-0)

7.2.1 I ²C write operation

The write operation is a single continuous transaction:

- The I^2C master sends the START (S) condition which blocks the bus.
- The I²C Master sends the 7-bit slave address and 0 into the R bit (indicates a write transaction, the byte sent would be 0x40). The transaction will be acknowledged by the slave (ACK).
- The I²C Master then sends the address of the first register to write. The transaction will be acknowledged by the slave (ACK). (or not acknowledged (NACK) when the address is not writable)
- The I²C Master then sends one or more data bytes which are written into sequential registers (if valid) until the transaction is concluded with a STOP (P) condition.

From slave to master

Figure 15: I²C Write operation

7.2.2 I ²C read operation

A *read* transaction (see [Figure 16\)](#page-18-2) starts with a write (of the register address), followed by a read. Consequently, it has the following format:

The write specifies the register address:

- The I²C Master sends a START condition.
- The I²C Master sends the 7-bit slave address and 0 into the R bit (indicates a write transaction, the byte sent would be 0x40). The transaction will be acknowledged by the slave (ACK).
- The I²C Master then sends the address of the first register to read.

It is followed by the read sequence:

- The I²C Master sends again a START condition.
- The I²C Master sends the 7-bit slave address and 1 into the R bit (indicates a read transaction, the byte sent would be 0x41).
- The 1^2C slave then sends 1-n data bytes from sequential registers (if valid), each acknowledged by the master until the transaction is concluded with a STOP condition.

Figure 16: I²C read operation

7.2.3 High speed mode

The bus operation speed is limited to 400 kHz unless a high speed enable command (00001xxx) is issued by the master device as the first byte after START condition. This command is not

acknowledged (NACK) by the slave. The high-speed operation allows data transfer frequencies up to 3.4 MHz. The input filters on the serial interface (SDA and SCL) are adapted to a higher bandwidth. After the high-speed command, the master transmits the slave address to invoke a data transfer. The bus keeps operating at the highest operating frequency until the master issues a STOP condition. Upon reception of the STOP condition by the slave, the input filters are switched to their initial time constants, which allow only up to 400 kHz transfer rates.

From master to slave

From slave to master

Figure 17: I²C high-speed read operation

7.2.4 Timing specifications

ENS220 is compliant to the I^2C bus specifications [UM10204, I^2C -bus specification and user manual, Rev. 6, 4 April 2014].

Table 7: ENS220 I ²C timing parameters⁹

⁹ All values referred to min V_{H} and max V_{II} levels in [Table 3.](#page-7-1)

Figure 18: I²C timing diagram

7.3 SPI interface

The ENS220 is an SPI bus slave. The SPI allows the user to write and read the registers of the device. The serial interface interacts with the outside world by four wires: CSN, SCLK, SDI and SDO. The optional three-wire mode uses the single bi-directional data line SDI instead of the two lines SDI and SDO.

Note: Use the SPI three-wire mode if multiple devices are to be used on the same SPI bus. The ENS220 pulls the SDO line low when CSN is high, preventing communication with other devices on the bus.

CSN is the serial port enable and it is controlled by the SPI master. It is driven low at the start of the SPI frame and returns high at the end.

SCLK is the serial port clock and is controlled by the SPI master. It should stay high in the absence of transmissions. SDI and SDO are respectively the serial port data input, and the output. Those lines are driven at the falling edge of SCLK and should be captured at the rising edge of SCLK.

The SDO pin is shared between SPI output data and interrupt function. When CSN is high and interrupt functionality is enabled, SDO will provide interrupt service.

If interrupts are disabled, then SDO stays low until data is requested from the device, i.e., during an SPI transaction.

The read register and write register commands are both completed in 16 clock pulses or in multiples of 8 in the case of multiple bytes read or write. The bit duration is the time between two falling edges of SCLK. The first bit (bit 0) starts at the first falling edge of SCLK after the falling edge of CSN while the last bit (bit 15, bit 23, ...) starts at the last falling edge of SCLK just before the rising edge of CSN.

Figure 19: Minimum SPI frame

The device can also work with a low idle value of SCLK (also known as SPI mode 0), as shown below.

Figure 20: SPI frame using mode 0

A standard SPI frame is organized as follows in [Table 8.](#page-21-0)

Table 8: SPI frames for reading and writing registers

	Bit	Name	Description			
Byte			read	write		
$\mathbf 0$	7:2	AD[5:0]	Address of the indexed register			
$\mathbf{0}$	1	MS	0: address will be auto incremented in multiple read/write commands. 1: no auto-incrementing of the address			
0	$\mathbf{0}$	RW	1: data Di is read from the device. SDO becomes active at bit 8.	0: data Di is written to the device.		
1	15:8	D1[7:0]	Data output from the device (MSB first) to pin SDO.	Data written to the device from pin SDI (MSB first)		
\cdots						
η	$(8 \times n + 7)$: 8×n	Dn	<i>n</i> -th byte output to pin SDO (MSB first)	n -th byte input from pin SDO (MSB) first)		

In multiple read/write commands, further blocks of 8 clock periods are added. When the MS bit is 0, the address used to read/write data remains the same for every block. When MS bit is 1, the address used to read/write data is increased at every block. The function and the behaviour of SDI and SDO remain unchanged.

7.3.1 SPI write operation

The SPI single byte write command consists of 16 clock pulses. A multiple byte write is performed by adding blocks of 8 clock pulses to the single byte write.

Figure 21: Single byte write

Figure 22: Multiple bytes write (2 bytes)

7.3.2 SPI read operation

The SPI single byte read command consists of 16 clock pulses. A multiple byte read is performed by adding blocks of 8 clock pulses to the single byte read. All register data is copied into an intermediate buffer at the beginning of a read transaction; multiple reads in the same read transaction will refer to the intermediate buffer.

Figure 23: SPI read timing diagram

Figure 24: Multiple byte SPI read (2 bytes)

A 3-wire SPI mode can be selected by setting bit SPI3 in the INTF_CFG register. In this case, SDA acts as a bi-directional data line, and should be connected to an external pull-up resistor. Multiple byte read is also available in 3-wire mode.

Figure 25: SPI read in 3-wire mode

7.3.3 Timing specifications

Figure 26: SPI timing diagram

8 Registers

This section describes the registers of the ENS220.

8.1 Register map

Table 9: Register map

Legend: *(the letters in the R/W column define the colours of the register fields)*

- -

W Write access in low power mode w Write access in ultra-low power mode 0 Must write 0

R Read access in low power mode r Read access in ultra-low power mode 0 Reads 0 R Read access in low power mode \overline{r} Read access in ultra-low power mode

F Address counter wraps. See text. $\forall y$ Read only the last value in ultra-low power mode

Note that some registers are spread over multiple addresses. For example, [PART_ID](#page-26-1) at address 0 is spread over 2 addresses (its "Size" is 2). Registers are stored in little endian so the LSB of [PART_ID](#page-26-1) is at address 0 and the MSB of [PART_ID](#page-26-1) is at address 1.

- **8.2 Detailed register description**
	- **8.2.1 PART_ID (Address 0x00-0x01)**

The value is available when the ENS220 is initialized after power-up.

Table 10: Register PART_ID

8.2.2 UID (Address 0x02-0x05)

32 bit unique device identifier

Table 11: Register UID

8.2.3 MODE_CFG (Address 0x06)

Table 12: Register MODE_CFG

Table 13: Measurement selection with MEAS_T and MEAS_P

8.2.4 MEAS_CFG (Address 0x07)

Table 14: Register MEAS_CFG

Table 15: Typical pressure ADC conversion time

[CONTENTS PAGE](#page-2-1) $\left\langle \right\rangle$

Table 16: PT_RATE

8.2.5 STBY_CFG (Address 0x08)

Table 17: Register STBY_CFG

Table 18: Standby pauses in-between measurements

8.2.6 OVS_CFG (Address 0x09)

Oversampling measures the average over of a certain number of samples. Oversampling applies to all measurement modes.

Table 19: Register OVS_CFG

Table 20: Oversampling of pressure measurements

Table 21: Oversampling of temperature measurements

8.2.7 MAVG_CFG (Address 0x0A)

Moving average configuration

Table 22: Register MAVG_CFG

Table 23: Moving average configuration

8.2.8 INTF_CFG (Address 0x0B)

Host interface configuration register

Table 24: Register INTF_CFG

8.2.9 INT_CFG (Address 0x0C)

Interrupt configuration register.

Table 25: Register INT_CFG

8.2.10 PRESS_LO (Address 0x0D-0x0F)

This 3-byte register sets the pressure threshold for the low-pressure interrupt.

Table 26: Register PRESS_LO

8.2.11 PRESS_HI (Address 0x10-0x12)

This 3-byte register sets the pressure threshold for the high-pressure interrupt.

Table 27: Register PRESS_HI

8.2.12 FIFO_CFG (Address 0x13)

FIFO configuration register

Table 28: Register FIFO_CFG

8.2.13 DATA_STAT (Address 0x14)

Data status register

Table 29: Register DATA_STAT

8.2.14 FIFO_STAT (Address 0x15)

FIFO status register

Table 30: Register FIFO_STAT

8.2.15 INT_STAT (Address 0x16)

Interrupt status register. Each bit except IA is set if the corresponding interrupt source has generated an event, even if the hardware interrupt is disabled by the INT CFG register. Reading this register will clear all flags.

Table 31: Register FIFO_STAT

8.2.16 PRESS_OUT (Address 0x17-0x19)

This 3-byte register contains a 24-bit unsigned integer representing the pressure in 1/64 Pa.

A read on this register extracts one element from the FIFO if the FIFO is enabled by [FIFO_MODE](#page-27-0) = 1. When the FIFO is empty, the read returns 0x000000. [HP](#page-27-0) = 1 must be set for reading from the FIFO.

When the FIFO is not enabled (bypass or moving average), reads from this register return the latest measurement result. If readouts occur faster than measurements, values are repeated.

To ensure a consistent value during readout, [PRESS_OUT](#page-39-1) registers are double buffered. When [PRESS_OUT_XL](#page-39-1) is read, the device copies all bytes from the internal measurement registers to the I^2C registers, then reads are always directly from the I^2C/SPI registers. The double buffering is thus only available if all PRESS OUT registers are read within the same I²C or SPI transaction (see sections

[7.2.2,](#page-18-0) [7.3.2\)](#page-22-1). If the application does not support reading multiple bytes at once, then the user must ensure that the PRESS OUT register is not updated during the reading. This can be achieved by reading quickly after an interrupt occurred, or by using the single-shot mode (STBY CFG = 1).

Please note that the hardware implementation of this double buffering does not guarantee the alignment between data ready flags and data if they are accessed in the same I^2C/SPI transaction. It is advised to access the flags in a separate transaction.

Table 32: Register PRESS_OUT

Example: For a stored [PRESS_OUT](#page-39-1) value of 0x62F340 the absolute pressure in Pa is calculated as follows:

$$
P = \frac{0 \times 062 \times 340}{64} \text{ Pa} = 101325 \text{ Pa}
$$

See section [6.3.1](#page-11-1) for further information.

8.2.17 TEMP_OUT (Address 0x1A-0x1B)

This 2-byte register contains a 16-bit unsigned integer representing the temperature in 1/128 K.

Reads from this register return the latest measurement result. If reads occur faster than measurements, values are repeated.

To ensure a consistent value during readout, [TEMP_OUT](#page-40-0) registers are double buffered. When [TEMP_OUT_L](#page-40-0) is read, the device copies all bytes from the internal measurement registers to the I^2C/SPI registers, then readouts are always directly from the I^2C/SPI registers. The hardware implementation does to guarantee the alignment between data ready flags and data if they are accessed in the same l^2C or SPI transition; it is advised to access the flags separately from the data. But please note that double buffering only works for [TEMP_OUT](#page-40-0) if [TEMP_OUT_L](#page-40-0) and [TEMP_OUT_H](#page-40-0) are read in the same I^2C or SPI transaction with auto-increment of the register address (see [7.2.2\)](#page-18-0).

Table 33: Register TEMP_OUT

Example: For a stored [TEMP_OUT](#page-40-0) value of 0x9513, the temperature in degrees Celsius is calculated as follows:

$$
T_C = \frac{0 \times 9513}{128} \text{K} - 273.15 \text{ K} \approx 25 \text{ °C}
$$

See section [6.3.2](#page-11-2) for further information.

8.2.18 PRESS_OUT_F (Address 0x27-0x29)

This register is the same as PRESS_OUT, except that reading in a single I^2C/SPI transaction wraps around from address $0x29$ to $0x27$. A single $1^2C/SPI$ transaction can thus read multiple P measurements from the FIFO.

The [HP](#page-27-0) bit of the [MODE_CFG](#page-27-1) register must be 1 when reading this register to access the FIFO.

Table 34: Register PRESS_OUT_F

- **9 Application information and use case examples**
- **9.1 I ²C operation circuitry (1.8 V)**

The recommended application circuit for the ENS220 l^2C interface operation is shown in [Figure 27.](#page-42-4)

Figure 27: Recommended application circuit for I ²C operation

Note(s):

- 1. CSN must always be high to ensure the I^2C mode. CSN can be connected directly to VDD.
- 2. Pull-up resistors.

The above recommendation for pull-up resistance values applies to I^2C standard mode only. Pull-up resistors for SCL and SDA are assumed to be part of the host system and should be selected dependent on the intended I^2C data rate and individual bus architecture.

- 3. A decoupling capacitor must be placed close to the VDD supply pin (pin 10) of the ENS220.
- 4. The INT pin is an output. If not used, it can be left unconnected.

9.2 I ²C operation circuitry (3.3 V)

The I^2C communication bus is 3.3 V tolerant. The power supply of the ENS220 requires a voltage regulator to 1.8 V.

Figure 28: Recommended application circuit for I²C operation with 3.3 V

Note(s):

- 1. If V_{DD} is switched off, SCL and SDA need to be set to GND (0 V)
- 2. CSN must always be high to ensure the I^2C mode. CSN can be connected directly to VDD.
- 3. Pull-up resistors. The above recommendation for pull-up resistance values applies to I^2C standard mode only. Pull-up resistors for SCL and SDA are assumed to be part of the host system and should be selected dependent on the intended I^2C data rate and individual bus architecture.
- 4. A decoupling capacitor must be placed close to the VDD supply pin (pin 10) of the ENS220.
- 5. The INT pin is an 1.8 V output. If not used, it can be left unconnected.

9.3 SPI operation circuitry

9.3.1 Three wire SPI

The recommended application circuit for the ENS220 for three wire SPI interface is shown in [Figure](#page-43-3) [29.](#page-43-3) The INT pin is an output for the interrupts. It can be left unconnected if it is not used.

Figure 29: Recommended application circuit (three wire SPI operation)

9.3.2 Four wire SPI

The recommended application circuit for the ENS220 for four wire SPI interface is shown in [Figure](#page-43-4) [30.](#page-43-4) The INT pin becomes the data output pin SDO.

Figure 30: Recommended application circuit (four wire SPI operation)

9.4 Recommended settings for different use cases

[Table 35](#page-44-2) lists relevant use cases with the associated configuration parameters and the expected performance with these settings.

NOTE: current consumption due to the communication interface used (I²C or SPI) is not included.

Table 35: Relevant use-cases with the associated configuration parameters and typical performance

9.5 Sample communication sequence for common tasks

The following code is a functional example and does not include error checking, so it is not suited for production.

The code uses the following instructions:

• Write (reg, value): write one byte "value" via the I2C or SPI bus to the device at register address "reg". The I2C device address is 0x20 which is different from the register address "reg" that addresses a register within the device. See section [7](#page-17-0) for details on how to address the device and registers within the device.

- Read(reg): read one byte from the device from register "reg".
- Read N (reg, count): read "count" bytes from the device, starting at register "reg". The register address is auto-incremented by the device.
- Wait(duration): Wait the specified amount of time ("duration")
- **9.5.1 Basic example using the single shot measurement mode**

```
Write(0x06, 0x08) // soft reset, equivalent to power-up
Wait(1 ms)
// *** configuration: shortest measurement time and one-shot ***
// (default is 2 ms + continuous measurements)
Write(0x06, 0x80) // enable all registers with bit HP=1
Wait(1 ms)
Write(0x07, 0x00) // 1 ms conversion time
Write(0x08, 0x01) // one-shot operation
Write(0x06, 0x00) // switch back to ultra-low power mode HP=0
                      // (this saves power if the measurement is triggered later)
Wait(1 ms) // wait a user-defined time until a measurement starts
// *** perform a measurement in ultra-low power mode ***
Write(0x06, 0x13) // start T+P measurement, ultra-low power, no FIFO
Wait(10 ms) // wait T+P measurement time (8 ms + margin)
// *** read the data ***
S = Read(0x14) // check PR & TR in DATA STAT to confirm that data is ready
If ((S \& 3) != 3)Print("Warning: measurement was not complete") }
buffer = ReadN(0x17, 5) // read all five data bytes (register 0x17 to 0x1B)
// *** convert, and print the data ***
T = buffer[3] | (buffer[4] << 8) // = buffer[0] + 256*buffer[1]
P = buffer[0] | (buffer[1] << 8) | (buffer[2] << 16)Print(P/64.0, "Pa")
Print(T/128.0 - 273.15, "C")
   9.5.2 Example using continuous mode with FIFO
Write(0x06, 0x08) // soft reset, equivalent to power-up
Wait(1 ms)
Write(0x06, 0x80) // enable all registers with HP bit
Wait(1 ms)
```

```
Write(0x07, 0x04) // 1ms measurement time, PT-rate 32
Write(0x09, 0x00) // OVSP 1X, OVST 1X
Write(0x0B, 0x04) // interrupt enabled
Write(0x0C, 0x50) // interrupt on TR and FIFO full
Write(0x06, 0xB3) // start measurement, P+T, FIFO enabled
// *** Repeat as long as measurements are required ***
     Wait(INT==1) // Wait until INT hardware pin is high
     S=Read(0x16) // INT STAT
     If (S & 0x40) { // TR flag: temperature ready
```



```
buffer = ReadN(0x1A, 2)        // read TEMP_OUT bytes
           T = buffer[0] | (buffer[1] << 8) // = buffer[0] + 256*buffer[1]
           Print(T/128.0 - 273.15, "C")
     }
     If (S & 0x10) { // FF flag: FIFO is full
           buffer = ReadN(0x27, 32*3) // read all data in FIFO
           for(i=0; i<32*3; i=i+3) {
             P = buffer[i] | (buffer[i+1] << 8) | (buffer[i+2] << 16)
           Print(P/64.0, "Pa")
           }
     }
// *** Turn off when measurements are not needed ***
Write(0x06, 0) //HP=0: put device in ultra-low power mode
```
[CONTENTS PAGE](#page-2-1)

10 Soldering information

The ENS220 uses an open LGA package. This package can be soldered using a standard reflow process in accordance with IPC/JEDEC J-STD-020E [\(Figure 31\)](#page-47-1). Devices have been verified against MSL1 storage conditions. Deviation from the recommended solder profile may result in degraded performance of the sensor. It is recommended to use a no-clean solder paste. There should not be any board washing processes, to prevent cleaning agents or other liquid materials contacting the sensor area.

Figure 31: Graph of the solder reflow profile

The detailed settings for the reflow profile are shown in [Table 36.](#page-47-2)

Table 36: Parameters of the solder reflow profile

Parameter	Reference	Value
Average temperature gradient in preheating		2.5 K/s
Soak time	t _{soak}	2.3 min
	Ts max	200 °C
Soak temp range	Ts min	150 °C
Time above 217 $°C$ (T1)	t ₁	Max. 60 s
Time above 230 $^{\circ}$ C (T2)	t ₂	Max. 50 s
Time above TPEAK -10 °C (T3)	t ₃	Max. 10 s
Peak temperature in reflow	TPEAK	260 °C
Maximum ramp-down rate for cooling to T1		Max. 5 K/s

- **11 Package drawings & markings**
- **11.1 Package outline dimensions**

Figure 32: LGA package drawing

Table 37: LGA package dimensions in mm

11.2 Landing pattern

ScioSense suggests a footprint (land pattern) on the PCB as depicted in [Figure 33](#page-49-1) (which is identical to the pad pattern in the outline drawing [Figure 32\)](#page-48-2). Please find the dimensions in [Table 37.](#page-49-2)

Figure 33: LGA land pattern (top view)

11.3 Device marking

Figure 34: LGA package marking

12 Ordering information

Table 38: Ordering information

13 RoHS Compliance & ScioSense Green Statement

RoHS: The term RoHS compliant means that Sciosense B.V. products fully comply with current RoHS directives. Our semiconductor products do not contain any chemicals for all 6 substance categories, including the requirement that lead does not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, RoHS compliant products are suitable for use in specified lead-free processes.

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15 Document status

Table 39: Document status

16 Revision information

Table 40: Revision history

Note(s) and/or Footnote(s):

- 1. Page and figure numbers for the previous version may differ from page and figure numbers in the current revision.
- 2. Correction of typographical errors is not explicitly mentioned.

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